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Quarterly Reliability Monitoring Results

Quarters: Q1/2021 to Q4/2021

Based on structural similarity

Supplier		User Part Number					
Nexperia B.V. Name of Laboratory Assembly reliability labs Based on AEC-Q101 Test		1PS10SB82 Part Description					
		MCD package					
		Test Conditions	Duration	# Lots	# Quantity	# Rejects	
			TEST				
	Pre- and Post-Stress						
# E1	Electrical Test	Tamb = 25 °C	N/A	see below	all parts	see below	
		JESD22-A113					
		Bake Tamb = 125 °C	24 hours				
	PC	Soak Tamb = 85 °C, RH = 85%	168 hours				
# A1	Preconditioning	Reflow soldering	3 cycles	113	9040	0	
		MIL-STD-750-1					
	HTRB	M1038 Method A					
	High Temperature Reverse						
# B1	Bias	reverse voltage ^[1]	1000 hours	116	9280	0	
	тс	JESD22-A104					
# A4	Temperature Cycling	-65 °C to Tjmax, not to exceed 150°C	1000 cycles	28	2240	0	
# A4	remperature cycing	JESD22-A102	1000 Cycles	20	2240	0	
	AC	Tamb = $121 ^{\circ}$ C, RH = $100 ^{\circ}$					
# A3 alt	Autoclave	Pressure = $205 \text{ kPa} (29.7 \text{ psia})$	96 hours	28	2240	0	
# AS dit	Autoclave		90 110015	20	2240	0	
	H3TRB	JESD22-A101					
	High Humidity High	Tamb = $85 ^{\circ}$ C, RH = 85% , VR = 80% of					
# A2 alt		rated reverse voltage ^{[1], [2]}	1000 hours	28	2240	0	
			1000 110015	20	2240	0	
	IOL	MIL-STD-750 Method 1037 ton = toff, devices powered to insure ΔT_j =					
# A5	INTERMITTER Operating Life		1000 hours	29	2320	0	
# A3	Internitient Operating Life	100 C 101 15000 Cycles	1000 Hours	29	2320	0	
	RSH	JESD22-A111					
# C8	Resistance to Solder Heat		10 s	n.a.	n a	n a	
+ 0	SD	200 0 - 5 0	10.2	11. d .	n.a.	n.a.	
# C10	Solderability	J-STD-002		63	630	0	
	1	des have to be considered (thermal runaway).		03	030	U	

[1] The physical limitations of Schottky diodes have to be considered (thermal runaway).

[2] The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

Calculation of FIT and MTTF

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1) Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

Wafer Fab	Technology	Quantity	Rejects	Failure Rate (FIT)	MTTF (hrs)
Nexperia DHAM	Schottky	9280	0	0.46	2.19E+09
	Beneticity	200	5		21152.05

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